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Hyperfast Rectifier, 30 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I _{F(AV)}	30 A								
V _R	600 V								
V _F at I _F at 125 °C	1.15 V								
t _{rr} (typ.)	25								
I _{FSM}	330								
T _J max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

FEATURES

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 123 °C, D = 0.50	30							
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	330	A						
Repetitive peak forward current	I _{FRM}	T _C = 123 °C, D = 0.50, f = 20 kHz	60							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS					
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-					
Forward voltage	VF	I _F = 30 A	-	1.3	1.6	V				
	۷F	I _F = 30 A, T _J = 125 °C	-	1.15	-					
Deverse leakers eurrent		$V_{R} = V_{R}$ rated	-	-	20					
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	Aų pA				
Junction capacitance	CT	V _R = 200 V	-	36	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}_F/\text{d}t = 100$) A/µs, V _R = 30 V	-	25	-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns			
		T _J = 125 °C		-	58	-				
Peak recovery current		T _J = 25 °C	I _F = 20 A, dI _F /dt = 1000 A/μs, V _B = 400 V	-	19	-	A			
Feak recovery current	I _{RRM}	T _J = 125 °C		-	32	-				
Reverse recovery charge	0	T _J = 25 °C		-	419	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1176	-				
		T _J = 25 °C		-	46	-	ns			
Reverse recovery time	t _{rr}	T _J = 125 °C		-	65	-				
Pack recover a surrent		T _J = 25 °C	$I_{\rm F} = 30 {\rm A},$	-	21	-	A			
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs, V _B = 400 V	-	36	-				
	0	T _J = 25 °C		-	550	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1560	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style: TO-247AD 2L	E5PH3006LH							

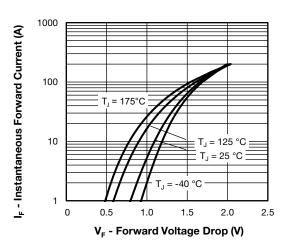


Fig. 1 - Forward Voltage Drop Characteristics

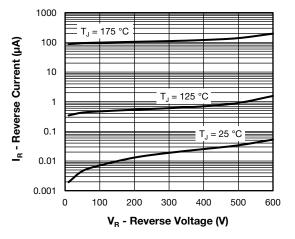


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



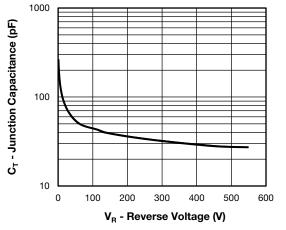


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

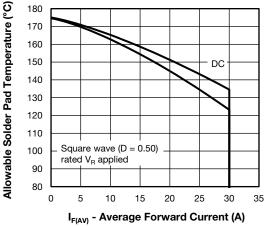


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

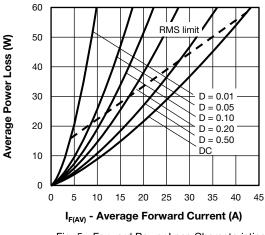


Fig. 5 - Forward Power Loss Characteristics

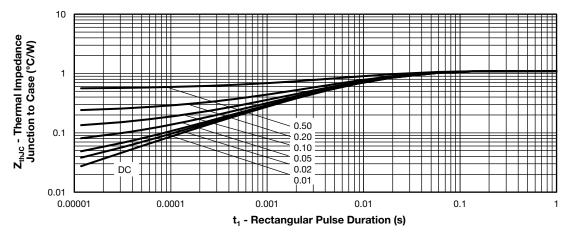


Fig. 6 - Transient Thermal Impedance, Junction to Case



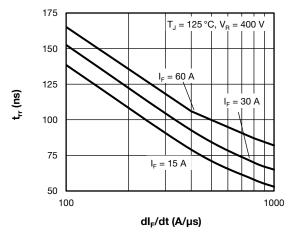


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

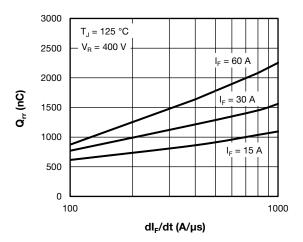


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

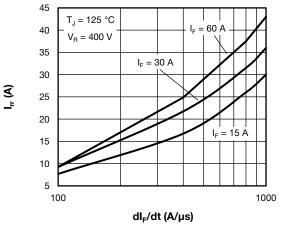


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt



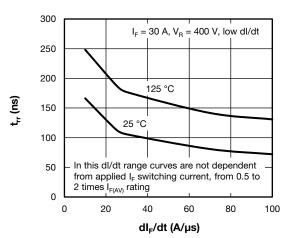
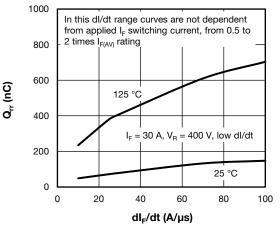


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





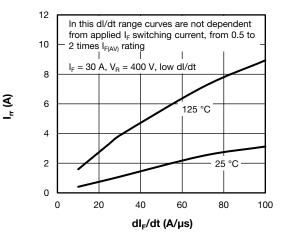


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

Revision: 18-May-2022

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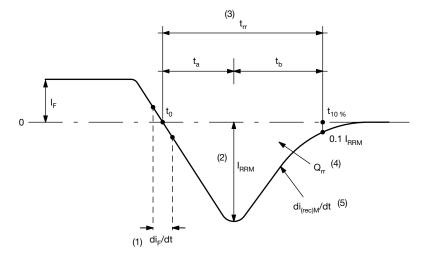


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- ⁽¹⁾ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM} ⁽⁴⁾ Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}





ORDERING INFORMATION TABLE

Device code	VS-	E	5	Р	н	30	06	L	Н	N3		
	1	2	3	4	5	6	7	8	9	10		
	1 -	 Vishay Semiconductors product 										
	2 -	 Circuit configuration E = single diode 										
	3 -		ED Pt [®] (
	4 -	- P=	TO-247	' packag	je							
	5	 Process type: H = hyperfast recovery 										
	6 -			ng (30 =	-							
	7 -	- Voltage rating (06 = 600 V)										
	8 -	- Package: L = long lead (TO-247AD)										
	9 -	- H = AEC-Q101 qualified										
	10 -			ntal digit en-free,		complia	nt, and	totally l	ead (Pb)-free		

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5PH3006LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95536						
Part marking information	www.vishay.com/doc?95648					



TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES SYMBOL	MILLIMETERS		INCHES		NOTES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055		ØК	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053			•		•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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